

TENTATIVE TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

TA8256BH**AUDIO POWER AMPLIFIER 6W × 3CH**

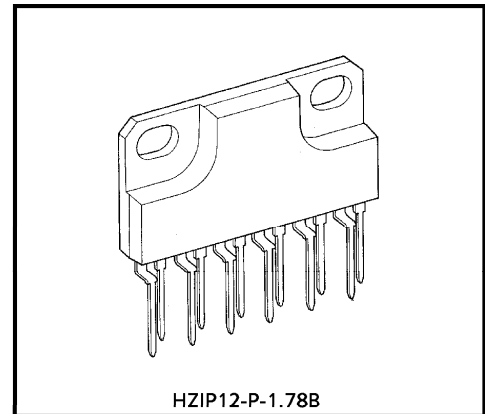
The TA8256BH is 3 channel audio power amplifier for Consumer applications.

This IC provides an output power of 6 watts per channel (at $V_{CC} = 20V$, $f = 1kHz$, $THD = 10\%$, $R_L = 8\Omega$)

It is suitable for power amplifier of TV and home Stereo.

FEATURES

- Built-in 3ch Amplifier
- High Output Power
: $P_{out} = 6W$ (Typ.)
($V_{CC} = 20V$, $R_L = 8\Omega$, $f = 1kHz$, $THD = 10\%$)
- Built-in Audio Muting Circuit.
- NF Terminal Capacitor Less
: Fixed Gain ($G_V = 34dB$), Needless External capacitor.
- Protectors
Thermal shut down Protection circuit, Over Voltage Protection circuit
- Low Popping Noise
- High THD Ratio
- High input dynamic range
- Available for using same PCB layout with 2 channel IC : TA8246H.
- Operating Supply Voltage Range
: $V_{CC(opr)} = 10 \sim 30V$ ($T_a = 25^\circ C$)



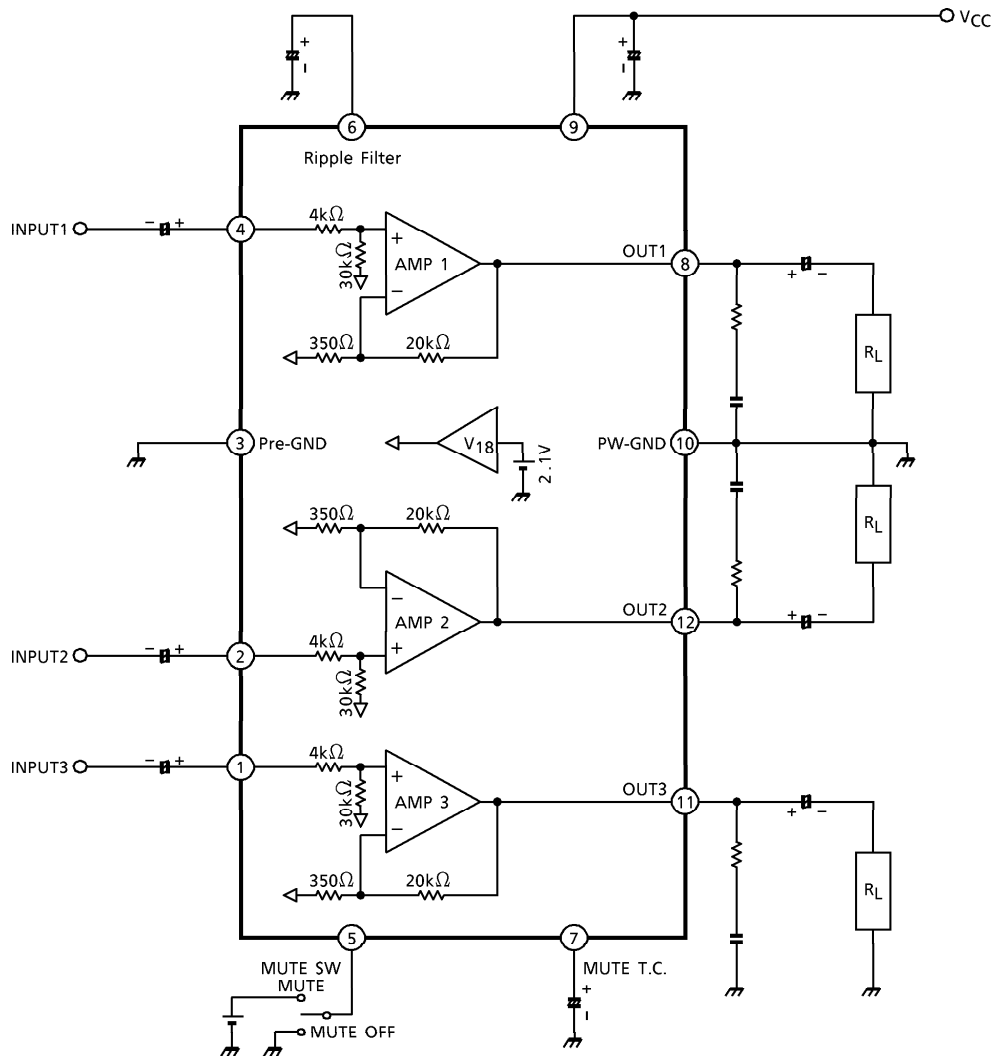
HZIP12-P-1.78B

Weight : 4.04g (Typ.)

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- This product generates heat during normal operation. However, substandard performance or malfunction may cause the product and its peripherals to reach abnormally high temperatures.
The product is often the final stage (the external output stage) of a circuit. Substandard performance or malfunction of the destination device to which the circuit supplies output may cause damage to the circuit or to the product.
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BLOCK DIAGRAM



TERMINAL EXPLANATION

TERMINAL No.	SYMBOL	FUNCTION	EQUIVALENT CIRCUIT
1	IN3	Input	
2	IN2		
4	IN1		
3	Pre-GND	GND terminal	—
5	MUTE. SW	MUTE control terminal	
7	MUTE. T.C		
6	RF	Ripple filter	
8	OUT1	Output	
11	OUT3		
12	OUT2		
9	V _{CC}	Supply voltage terminal	—
10	PW-GND	GND terminal	—

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V _{CC}	30	V
Output Current (Peak / Ch)	I _{O (peak)}	2	A
Power Dissipation	P _D (Note)	25	W
Operating Temperature	T _{opr}	- 20~75	°C
Storage Temperature	T _{stg}	- 55~150	°C

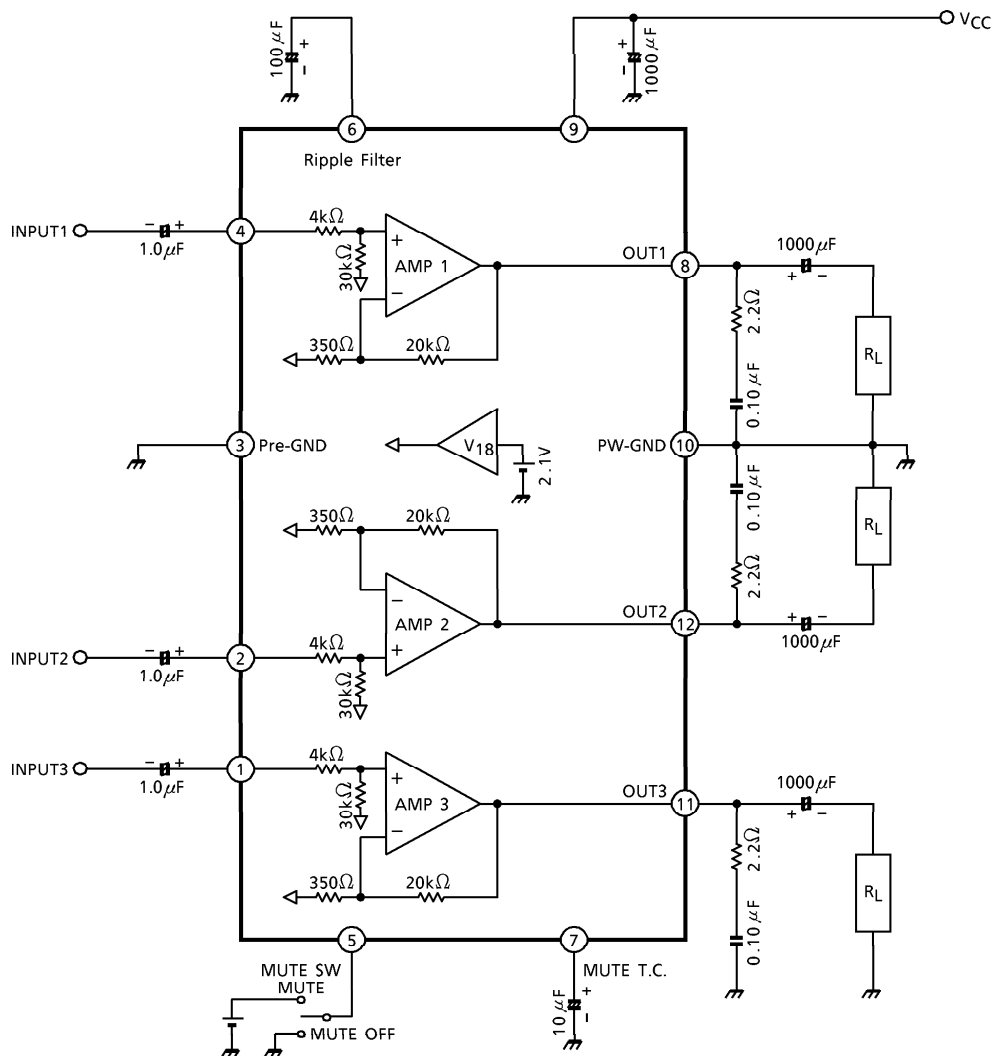
(Note) Derated above Ta = 25°C in the proportion of 200mW/°C.

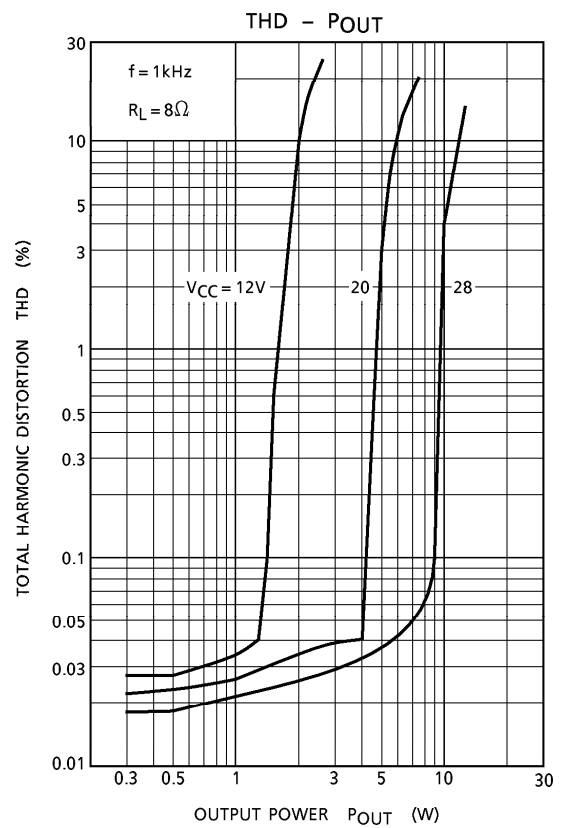
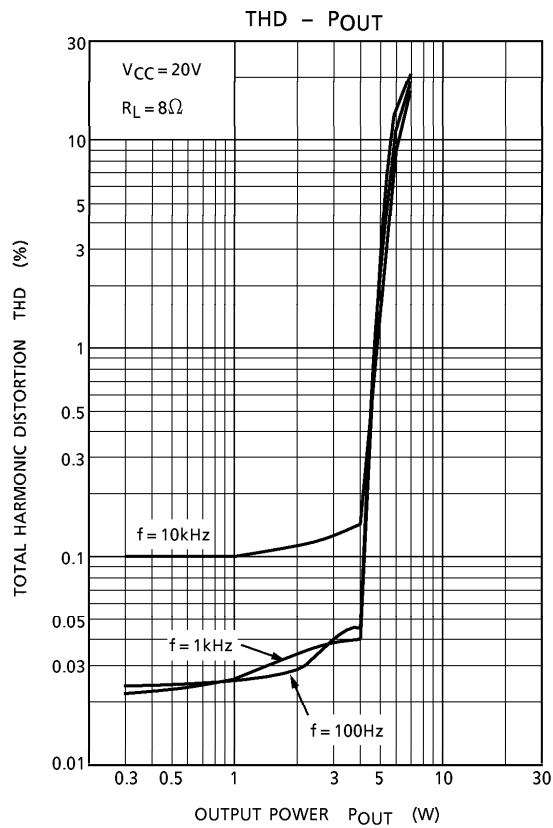
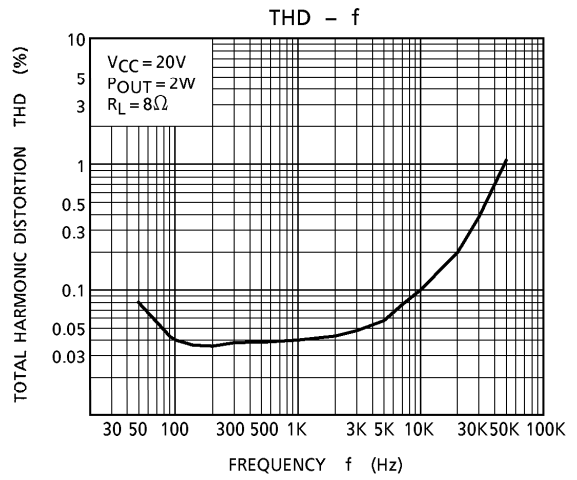
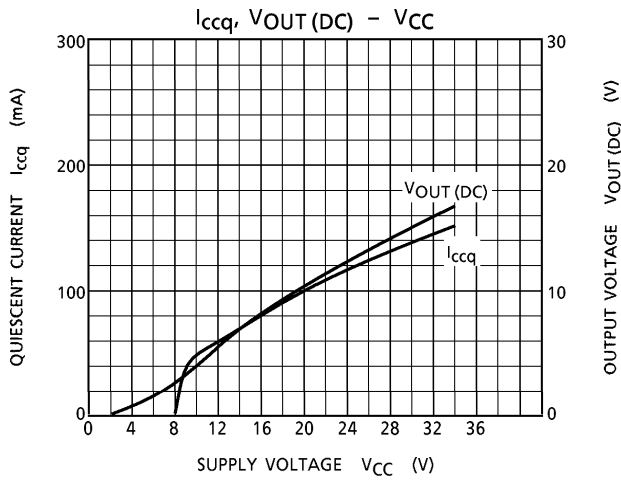
ELECTRICAL CHARACTERISTICS

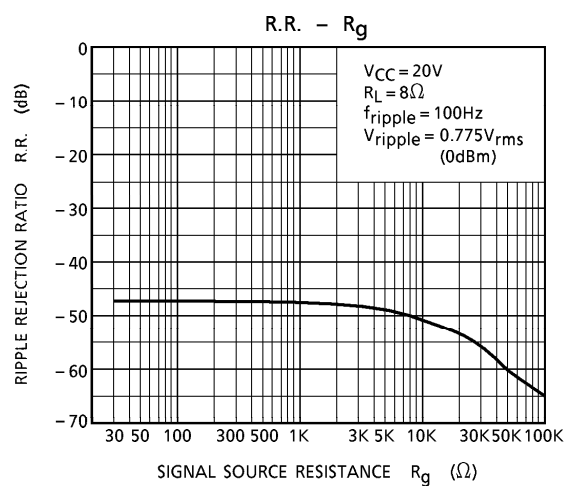
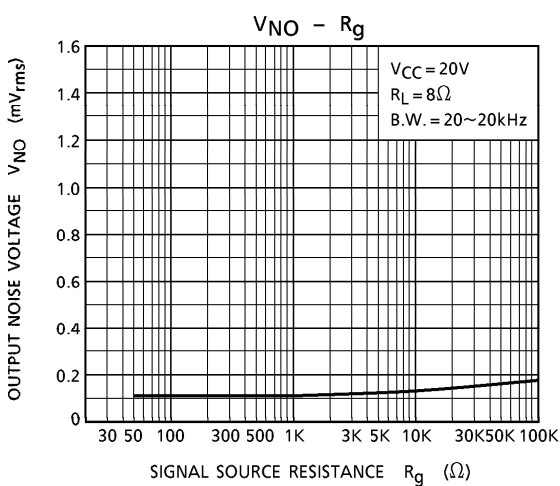
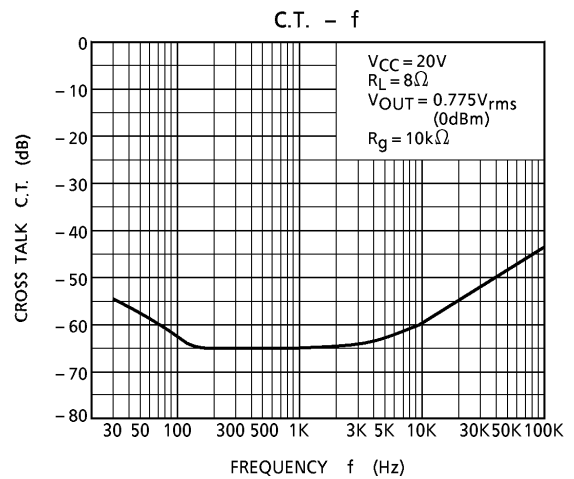
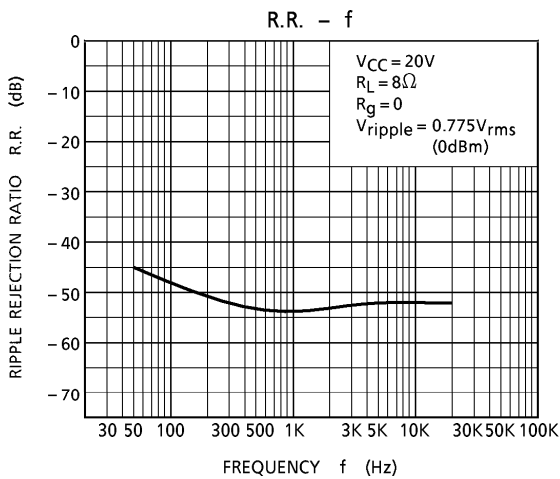
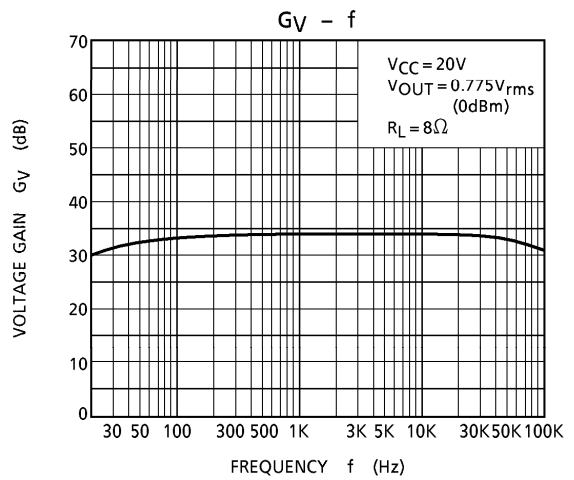
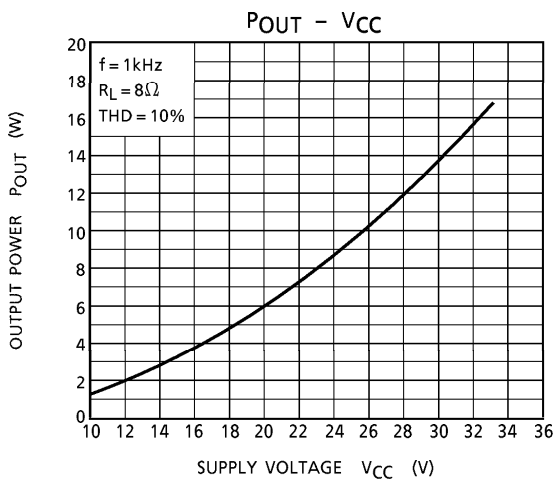
(Unless otherwise specified, V_{CC} = 20V, R_L = 8Ω, R_g = 620Ω, f = 1kHz, Ta = 25°C)

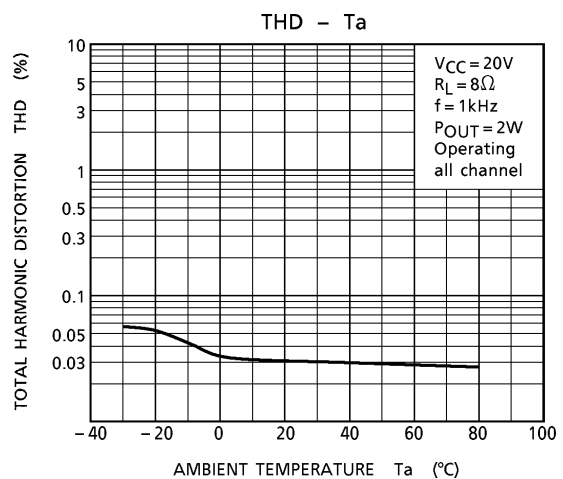
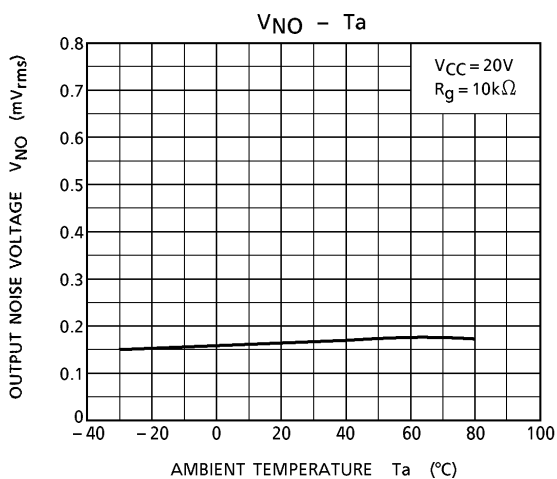
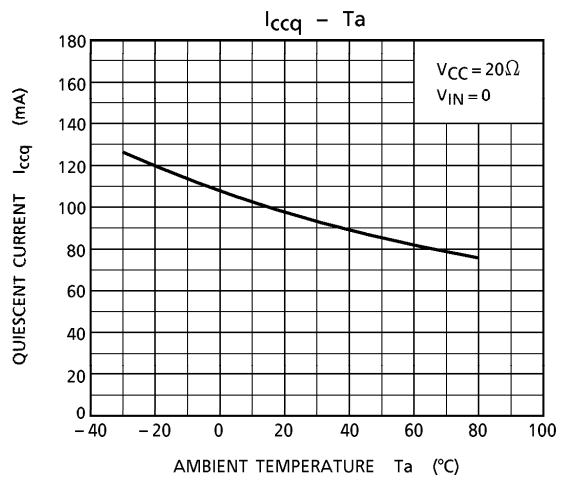
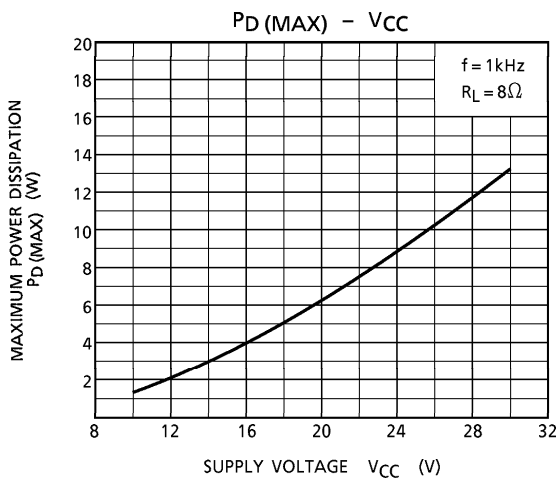
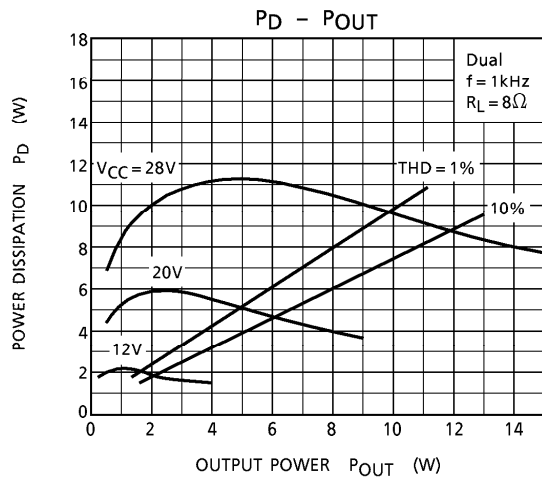
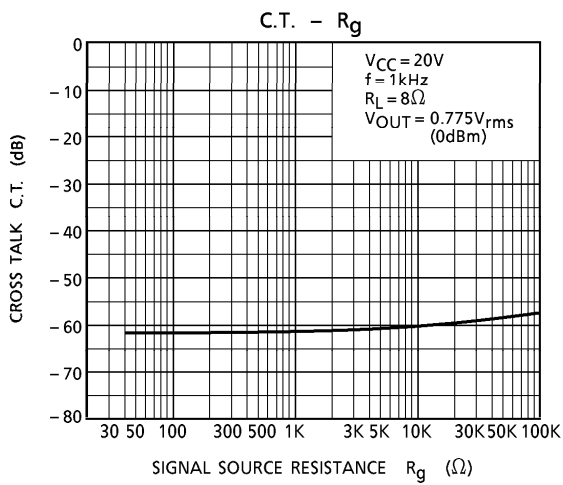
CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Quiescent Current	I _{ccq}	—	V _{in} = 0	65	100	180	mA
Output Power	P _{out} (1)	—	THD = 10%	5	6	—	W
	P _{out} (2)	—	THD = 1%	—	4.5	—	
Total Harmonic Distortion	THD (1)	—	P _{out} = 2W	—	0.04	0.2	%
	THD (2)	—	P _{out} = 2W, f = 10kHz	—	0.1	0.6	
Voltage Gain	G _v	—	V _{out} = 0.775V _{rms}	32.5	34	35.5	dB
Input Resistance	R _{in}	—	—	—	34	—	kΩ
Ripple Rejection Ratio	R.R.	—	f = 100Hz V _{ripple} = 0.775V _{rms}	- 40	- 47	—	dB
Output Noise Voltage	V _{no}	—	R _g = 10kΩ BW = 20Hz~20kHz	—	0.14	0.3	mV _{rms}
Cross Talk	C.T.	—	V _{out} = 0.775V _{rms}	—	- 60	—	dB
Mute Control Voltage	V _{th} (ON)	—	MUTE ON	3.1	—	V _{CC}	V
	V _{th} (OFF)	—	MUTE OFF	0	—	2.5	
Mute Attenuation Level	ATT	—	V _{out} = 0.775V _{rms} → MUTE	- 52	- 60	—	dB

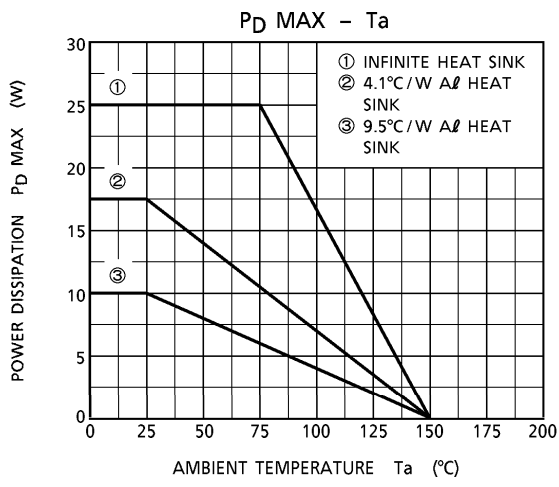
TEST CIRCUIT





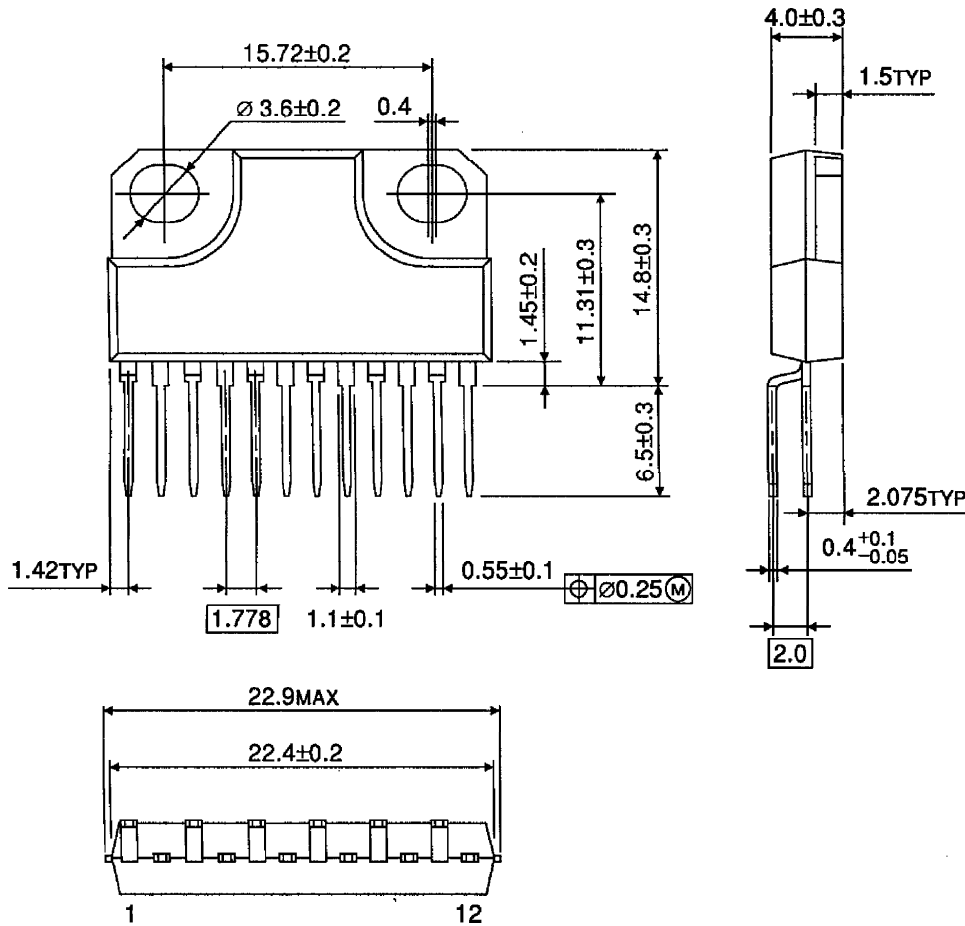






OUTLINE DRAWING
HZIP12-P-1.78B

Unit : mm



Weight : 4.04g (Typ.)